

LF147/LF347

Wide Bandwidth Quad JFET Input Operational Amplifiers

General Description

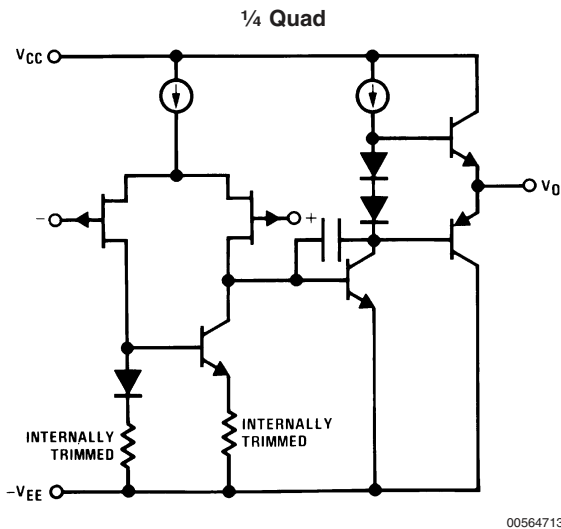
The LF147 is a low cost, high speed quad JFET input operational amplifier with an internally trimmed input offset voltage (BI-FET II™ technology). The device requires a low supply current and yet maintains a large gain bandwidth product and a fast slew rate. In addition, well matched high voltage JFET input devices provide very low input bias and offset currents. The LF147 is pin compatible with the standard LM148. This feature allows designers to immediately upgrade the overall performance of existing LF148 and LM124 designs.

The LF147 may be used in applications such as high speed integrators, fast D/A converters, sample-and-hold circuits and many other circuits requiring low input offset voltage, low input bias current, high input impedance, high slew rate and wide bandwidth. The device has low noise and offset voltage drift.

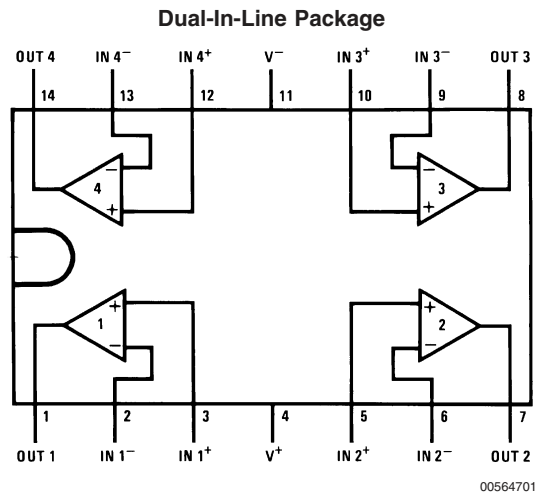
Features

- Internally trimmed offset voltage: 5 mV max
- Low input bias current: 50 pA
- Low input noise current: 0.01 pA/√Hz
- Wide gain bandwidth: 4 MHz
- High slew rate: 13 V/μs
- Low supply current: 7.2 mA
- High input impedance: 10¹²Ω
- Low total harmonic distortion: ≤0.02%
- Low 1/f noise corner: 50 Hz
- Fast settling time to 0.01%: 2 μs

Simplified Schematic



Connection Diagram



Note 1: LF147 available as per JM38510/11906.

Top View
Order Number LF147J, LF147J-SMD, LF347M,
LF347BN, LF347N, LF147J/883,
or JL147 BCA (Note 1)
See NS Package Number J14A, M14A or N14A

Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

	LF147	LF347B/LF347
Supply Voltage	±22V	±18V
Differential Input Voltage	±38V	±30V
Input Voltage Range (Note 3)	±19V	±15V
Output Short Circuit Duration (Note 4)	Continuous	Continuous
Power Dissipation (Notes 5, 11)	900 mW	1000 mW
T_j max	150°C	150°C
θ_{jA}		
Ceramic DIP (J) Package		70°C/W
Plastic DIP (N) Package		75°C/W
Surface Mount Narrow (M)		100°C/W
Surface Mount Wide (WM)		85°C/W

	LF147 (Note 6)	LF347B/LF347 (Note 6)
Operating Temperature Range		
Storage Temperature Range	-65°C ≤ T _A ≤ 150°C	
Lead Temperature (Soldering, 10 sec.)	260°C	260°C
Soldering Information		
Dual-In-Line Package		
Soldering (10 seconds)		260°C
Small Outline Package		
Vapor Phase (60 seconds)		215°C
Infrared (15 seconds)		220°C
See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.		
ESD Tolerance (Note 12)		900V

DC Electrical Characteristics (Note 7)

Symbol	Parameter	Conditions	LF147			LF347B			LF347			Units
			Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V _{OS}	Input Offset Voltage	R _S =10 kΩ, T _A =25°C Over Temperature		1	5		3	5		5	10	mV mV
ΔV _{OS} /ΔT	Average TC of Input Offset Voltage	R _S =10 kΩ		10			10			10		μV/°C
I _{OS}	Input Offset Current	T _J =25°C, (Notes 7, 8) Over Temperature		25	100		25	100		25	100	pA nA
I _B	Input Bias Current	T _J =25°C, (Notes 7, 8) Over Temperature		50	200		50	200		50	200	pA nA
R _{IN}	Input Resistance	T _J =25°C		10 ¹²			10 ¹²			10 ¹²		Ω
A _{VOL}	Large Signal Voltage Gain	V _S =±15V, T _A =25°C V _O =±10V, R _L =2 kΩ Over Temperature	50	100		50	100		25	100		V/mV
			25		25		15			V/mV		
V _O	Output Voltage Swing	V _S =±15V, R _L =10 kΩ	±12	±13.5		±12	±13.5		±12	±13.5		V
V _{CM}	Input Common-Mode Voltage Range	V _S =±15V	±11	+15		±11	+15		±11	+15		V
					-12			-12			-12	
CMRR	Common-Mode Rejection Ratio	R _S ≤10 kΩ	80	100		80	100		70	100		dB
PSRR	Supply Voltage Rejection Ratio	(Note 9)	80	100		80	100		70	100		dB
I _S	Supply Current			7.2	11		7.2	11		7.2	11	mA

AC Electrical Characteristics (Note 7)

Symbol	Parameter	Conditions	LF147			LF347B			LF347			Units
			Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
	Amplifier to Amplifier Coupling	$T_A=25^{\circ}\text{C}$, $f=1\text{ Hz}-20\text{ kHz}$ (Input Referred)		-120			-120			-120		dB
SR	Slew Rate	$V_S=\pm 15\text{V}$, $T_A=25^{\circ}\text{C}$	8	13		8	13		8	13		V/ μs
GBW	Gain-Bandwidth Product	$V_S=\pm 15\text{V}$, $T_A=25^{\circ}\text{C}$	2.2	4		2.2	4		2.2	4		MHz
e_n	Equivalent Input Noise Voltage	$T_A=25^{\circ}\text{C}$, $R_S=100\Omega$, $f=1000\text{ Hz}$		20			20			20		nV/ $\sqrt{\text{Hz}}$
i_n	Equivalent Input Noise Current	$T_j=25^{\circ}\text{C}$, $f=1000\text{ Hz}$		0.01			0.01			0.01		pA/ $\sqrt{\text{Hz}}$
THD	Total Harmonic Distortion	$A_V=+10$, $R_L=10\text{k}$, $V_O=20\text{ Vp-p}$, $\text{BW}=20\text{ Hz}-20\text{ kHz}$		<0.02			<0.02			<0.02		%

Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Note 3: Unless otherwise specified the absolute maximum negative input voltage is equal to the negative power supply voltage.

Note 4: Any of the amplifier outputs can be shorted to ground indefinitely, however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.

Note 5: For operating at elevated temperature, these devices must be derated based on a thermal resistance of θ_{JA} .

Note 6: The LF147 is available in the military temperature range $-55^{\circ}\text{C}\leq T_A\leq 125^{\circ}\text{C}$, while the LF347B and the LF347 are available in the commercial temperature range $0^{\circ}\text{C}\leq T_A\leq 70^{\circ}\text{C}$. Junction temperature can rise to $T_j\text{ max} = 150^{\circ}\text{C}$.

Note 7: Unless otherwise specified the specifications apply over the full temperature range and for $V_S=\pm 20\text{V}$ for the LF147 and for $V_S=\pm 15\text{V}$ for the LF347B/LF347. V_{OS} , I_B , and I_{OS} are measured at $V_{CM}=0$.

Note 8: The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature, T_j . Due to limited production test time, the input bias currents measured are correlated to junction temperature. In normal operation the junction temperature rises above the ambient temperature as a result of internal power dissipation, P_D . $T_j=T_A+\theta_{JA} P_D$ where θ_{JA} is the thermal resistance from junction to ambient. Use of a heat sink is recommended if input bias current is to be kept to a minimum.

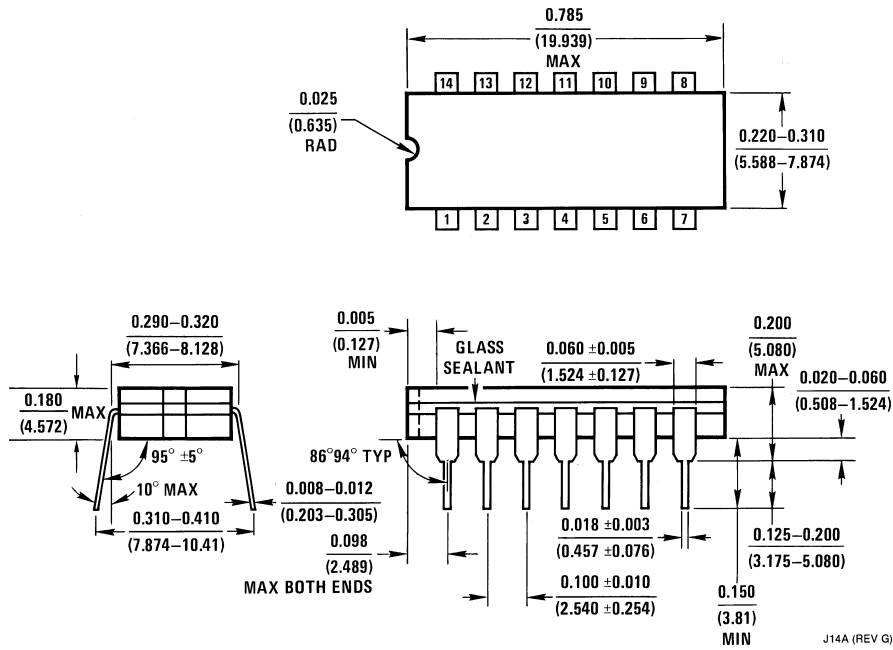
Note 9: Supply voltage rejection ratio is measured for both supply magnitudes increasing or decreasing simultaneously in accordance with common practice from $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ for the LF347 and LF347B and from $V_S = \pm 20\text{V}$ to $\pm 5\text{V}$ for the LF147.

Note 10: Refer to RETS147X for LF147D and LF147J military specifications.

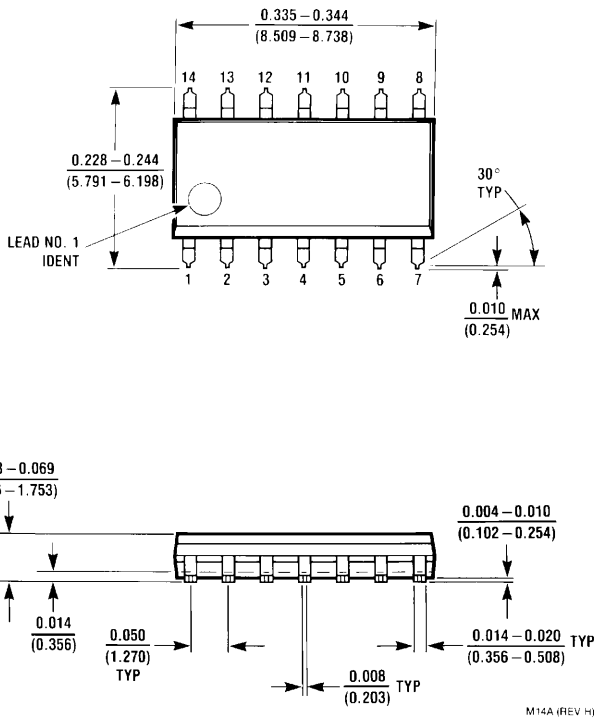
Note 11: Max. Power Dissipation is defined by the package characteristics. Operating the part near the Max. Power Dissipation may cause the part to operate outside guaranteed limits.

Note 12: Human body model, $1.5\text{ k}\Omega$ in series with 100 pF .

Physical Dimensions inches (millimeters) unless otherwise noted

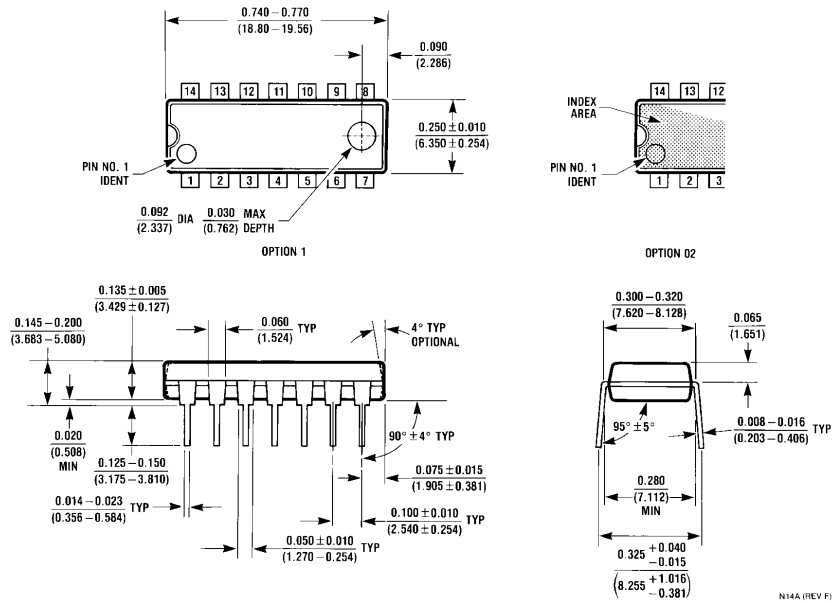


Ceramic Dual-In-Line Package (J)
 Order Number LF147J, LM147J-SMD or LF147J/883
 NS Package Number J14A



S.O. Package (M)
 Order Number LF347M or LF347MX
 NS Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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